

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	408	semiconductor and ((porous adj film) with dielectric)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/01 09:46
L2	14	L1 and (micelle with surfactant)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/01 09:46
L3	1	L2 and (diazo or diazonium or (nitrogen with organic with radical))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/01 09:46
L4	1	((semiconductor and porous) and (silicone with resin) and (micelle adj forming) and pyrolysis).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/01 10:01
L5	469	Hamada.in. and dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/01 10:01
L6	1	5 and (micelle and diazo)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/01 10:02
L7	48	5 and (porous with dielectric)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/01 10:02
L8	22	7 and organic	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/01 10:02
L9	5	("5494859" "6197913" "6313045" "6359096" "6596404").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/03/01 10:04
S1	3	(semiconductor and porous) and (silicone with resin) and (micelle adj forming) and pyrolysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/01 10:01

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S2	1	(semiconductor and porous) and (silicone with resin) and (micelle adj forming) and diazo	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/27 13:40
S3	85	(semiconductor and porous) and (silicone with resin) and diazo	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/27 13:40
S4	31	S3 and dielectric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/27 13:44
S5	408	semiconductor and ((porous adj film) with dielectric)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/27 14:11
S6	14	S5 and (micelle with surfactant)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/27 13:50
S7	1	S6 and (diazo or diazonium or (nitrogen with organic with radical))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/01 09:46
S8	64	S5 and polymeric	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/27 13:53
S9	0	S8 and (diazo or diazonium or (nitrogen with organic with radical))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/27 13:50
S10	54	S5 and (silicone or silane) and (polymeric or colloidal or diazo)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/27 14:13
S11	37	S10 and dielectric.ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/27 14:13

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S12	1	"5494858".PN.	USPAT; USOCR	OR	ON	2006/02/27 14:17
S13	9	(US-20040188846-\$ or US-20050089642-\$).did. or (US-6998148-\$ or US-6770572-\$ or US-6737118-\$ or US-6602804-\$ or US-6589644-\$ or US-6413882-\$ or US-6171645-\$).did.	US-PGPUB; USPAT	OR	ON	2006/02/27 14:18
S14	3625	257/758.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/27 14:30
S15	576	257/759.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/27 14:38
S16	826	257/410.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/27 14:44
S17	1171	257/506.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/27 14:54
S18	1278	257/701.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/27 14:54
S19	9	(US-20040188846-\$ or US-20050089642-\$).did. or (US-6998148-\$ or US-6770572-\$ or US-6737118-\$ or US-6602804-\$ or US-6589644-\$ or US-6413882-\$ or US-6171645-\$).did.	US-PGPUB; USPAT	OR	ON	2006/02/27 15:04